# P26B10SL

Power MOSFETs 100V, 26A, N-channel

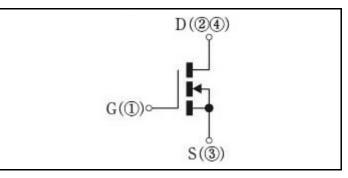
# Feature

- N-channel
- SMD
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Pb free terminal
- · RoHS:Yes

#### OUTLINE



# **Equivalent circuit**



# Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperrature	Tstg		-55 to 150	°C
Channel tempertature	Tch		-55 to 150	°C
Drain-source voltage	V <sub>DSS</sub>		100	V
Gate-source voltage	V <sub>GSS</sub>		±20	V
Continuous drain current(DC)	I <sub>D</sub>		26	А
Continuous drain current(Peak)	I <sub>DP</sub>	Pulse width 10µs, duty=1/100	78	А
Total power dissipation	P <sub>T</sub>		44	W
Single avalanche current	I <sub>AS</sub>	Starting Tch=25°C Tch≦150°C	19	А
Single avalanche energy	E <sub>AS</sub>	Starting Tch=25°C Tch≦150°C	40	mJ

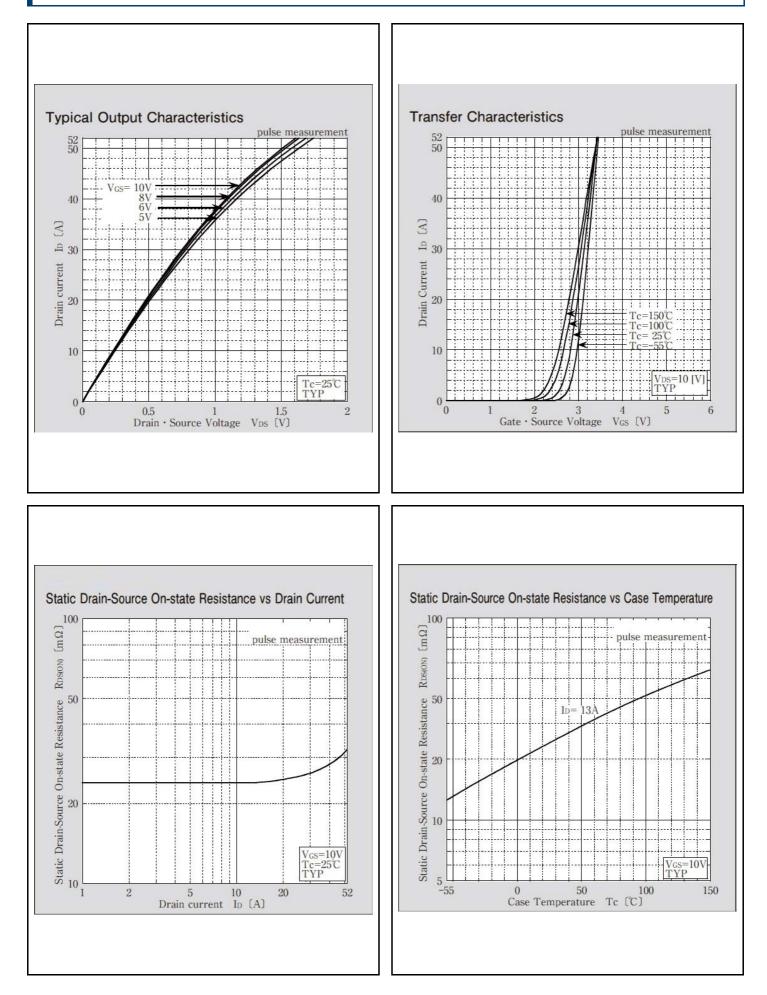
\* : See the original Specifications

<b>Electrical Characteristics</b>	(unless otherwise specified : Tc=25°C)

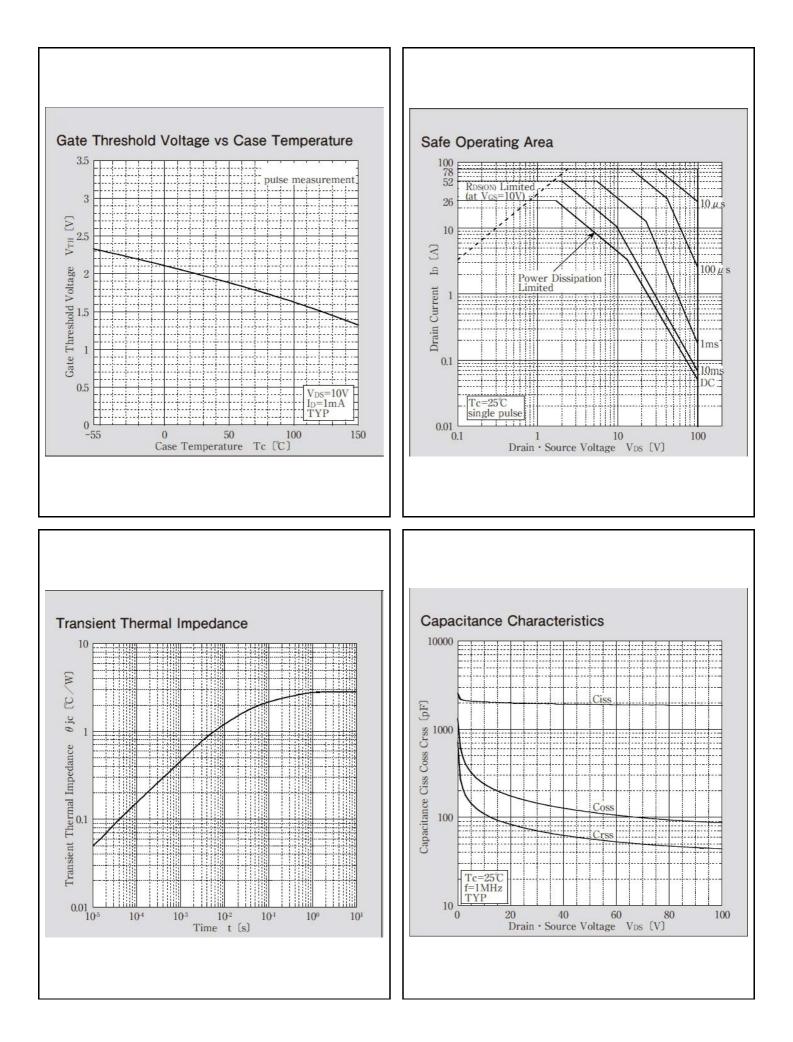
	Symbol	Conditions		Ratings		
Item			MIN	ТҮР	MAX	Unit
Drain-Source breakdown voltage	V <sub>(BR)DSS</sub>	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	I <sub>DSS</sub>	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	I <sub>GSS</sub>	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g <sub>fs</sub>	ID=13A, VDS=10V	8	16		S
Static drain-source on-state resistance	R <sub>DS(ON)</sub>	ID=13A, VGS=10V		0.024	0.03	Ω
Static drain-source on-state resistance	R <sub>DS(ON)</sub>	ID=13A, VGS=4.5V		0.026	0.035	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	V <sub>SD</sub>	IS=26A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case, with heatsink $st$			2.84	°C/W
Total gate charge	Qg	VDD=80V, VGS=10V, ID=26A		43		nC
Gate to source charge	Qgs	VDD=80V, VGS=10V, ID=26A		9		nC
Gate to drain charge	Qgd	VDD=80V, VGS=10V, ID=26A		12		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		1975		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		76		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		158		pF
Turn-on delay time	td(on)	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		6		ns
Rise time	tr	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		10		ns
Turn-off delay time	td(off)	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		30		ns
Fall time	tf	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		17		ns
Diode reverse recovery time	trr	IF=26A, VGS=0V, di/dt=100A/µs		53		ns
Diode reverse recovery charge	Qrr	IF=26A, VGS=0V, di/dt=100A/µs		100		nC

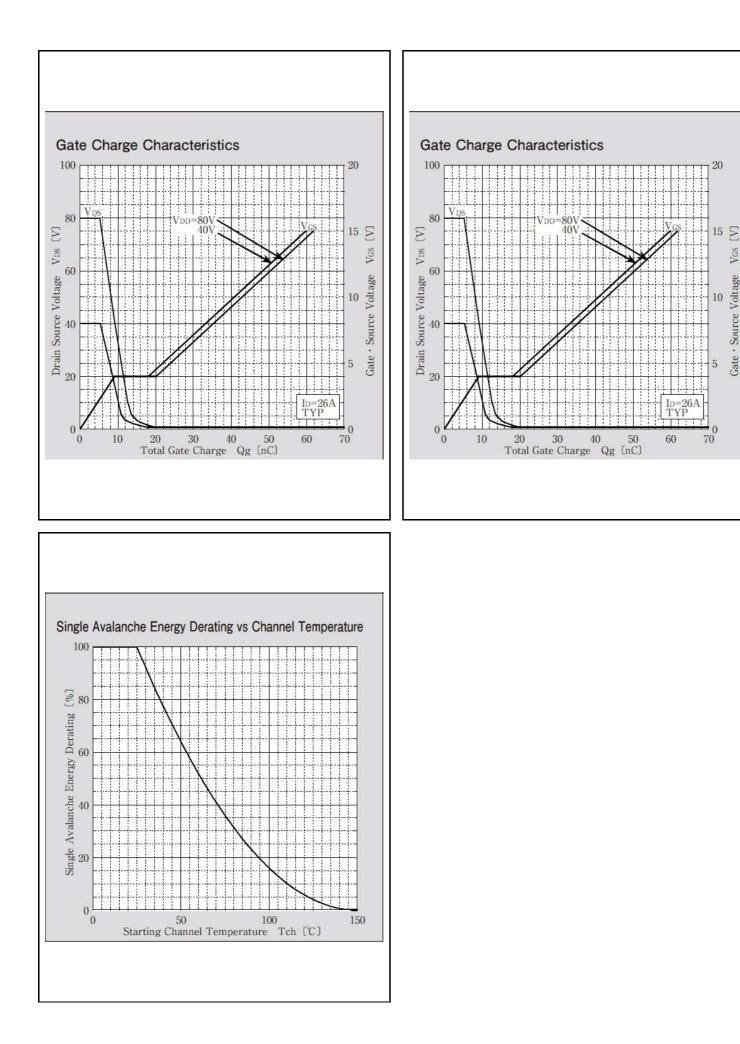
\* : See the original Specifications

# **CHARACTERISTIC DIAGRAMS**



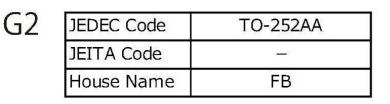
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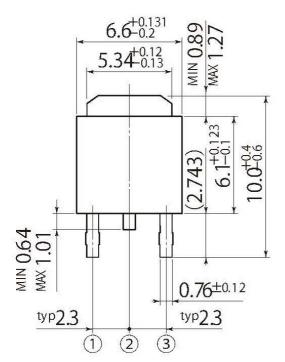


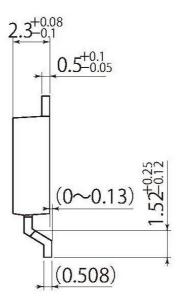


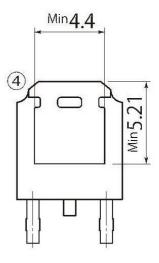
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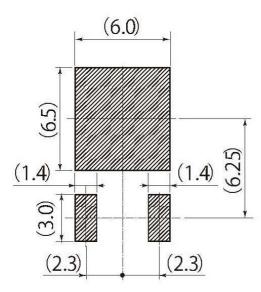
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**Referential Soldering Pad** 

• Optimize soldering pad to the board design and soldering condition.

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